

#### **General Description**

The MAX3610 is a low-jitter, high-performance, dual-rate clock generator optimized for 1Gbps/2Gbps/4Gbps Fibre-Channel applications. When connected with an external AT-cut crystal, the device generates a precision clock output by integrating a crystal oscillator with Maxim's low-noise phase-locked loop (PLL) providing a low-cost solution. By coupling Maxim's low-noise PLL design featuring a low-jitter generation VCO with an inexpensive fundamental mode crystal, the MAX3610 provides the optimum combination of low cost, flexibility, and high performance.

The MAX3610 output frequency is selectable. When using a 26.5625MHz crystal, the output clock rate can be set to either 106.25MHz or 212.5MHz. When operating at 106.25MHz, the typical phase jitter is 0.7ps<sub>RMS</sub> from 12kHz to 20MHz. The MAX3610A has low-voltage positive-emitter-coupled logic (LVPECL) clock output drivers. The MAX3610B has low-voltage differential-signal (LVDS) clock output drivers. The MAX3610 output drivers can also be disabled.

The MAX3610 operates from a single +3.3V supply. The PECL version typically consumes 165mW, while the LVDS version typically consumes 174mW. Both devices are available in die form and have a 0°C to +85°C operating temperature range.

### **Applications**

Fibre-Channel Hard Disk Drives Host Bus Adapters Raid Controllers

Fibre-Channel Switches

### **Features**

♦ Clock Output Frequencies: 106.25MHz or 212.5MHz

♦ Phase Jitter: 0.7psRMS **♦ LVPECL or LVDS Output** 

**♦** Excellent Power-Supply Noise Rejection

♦ Supply Current: 50mA at +3.3V Supply (LVPECL) 53mA at +3.3V Supply (LVDS)

♦ 0°C to +85°C Temperature Range

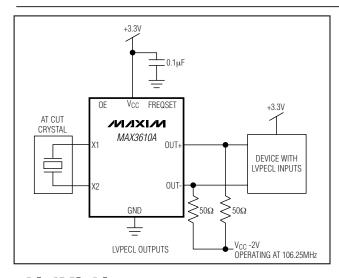
♦ Optional Output Disable

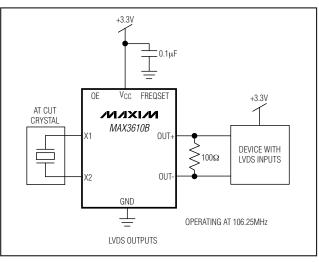
#### **Ordering Information**

PART	TEMP RANGE	PIN- PACKAGE	OUTPUTS
MAX3610AU/D	0°C to +85°C	Die	LVPECL
MAX3610BU/D	0°C to +85°C	Die	LVDS

Dice are designed to operate from 0°C to +85°C, but are tested and guaranteed only at  $T_A = +25^{\circ}C$ .

## **Typical Operating Circuits**





NIXIN

Maxim Integrated Products 1

#### **ABSOLUTE MAXIMUM RATINGS**

Supply Voltage	0.5V to (V <sub>CC</sub> + 0.5V) 0.5V to +0.8V	LVDS Output Voltage Operating Temperature Range Storage Temperature Range Processing Temperature	0°C to +85°C 65°C to +160°C
PECL Output Current		r recessing remperatareminim	

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

#### **ELECTRICAL CHARACTERISTICS**

 $(V_{CC} = +3.0V \text{ to } +3.6V, T_A = 0^{\circ}\text{C} \text{ to } +85^{\circ}\text{C}. \text{ Typical values are at } V_{CC} = +3.3V \text{ and } T_A = +25^{\circ}\text{C}, \text{ unless otherwise noted.})$  (Note 1)

PARAMETER	SYMBOL	CONDITION	ONS	MIN	TYP	MAX	UNITS	
0 1 0		(1)	LVPECL		50	65		
Supply Current	lcc	(Note 2)	LVDS		53	67	mA	
LVPECL OUTPUT SPECIFICATION	NS (Note 3)		•	•				
Output High Voltage	Vон	0°C to +85°C		V <sub>CC</sub> - 1.025		V <sub>CC</sub> - 0.88	V	
Output Low Voltage	V <sub>OL</sub>	0°C to +85°C		V <sub>CC</sub> - 1.81		V <sub>CC</sub> - 1.62	V	
LVDS OUTPUT SPECIFICATIONS	S (Figure 1)			•				
LVDS Output High Voltage	VoH					1.475	V	
LVDS Output Low Voltage	V <sub>OL</sub>			0.925			V	
LVDS Differential Output Voltage	IV <sub>OD</sub> I			250		400	mV	
LVDS Change in Magnitude of Differential Output for Complementary States	ΔIV <sub>OD</sub> I					25	mV	
LVDS Offset Output Voltage (Output Common-Mode Voltage)	Vos			1.125		1.275	V	
LVDS Change in Magnitude of Output Offset Voltage for Complementary States	ΔIV <sub>OS</sub> I					25	mV	
LVDS Differential Output Impedance				80	100	140	Ω	
LVDS Output Current		Outputs shorted together	•			12	mA	
CONTROL INPUT SPECIFICATION	NS (FREQSE	ET, OE)						
TTL Control Input-Voltage High	VIH			2			V	
TTL Control Input-Voltage Low	V <sub>IL</sub>					0.8	V	
Input Current (Input High)	lін			-10		+10	μΑ	
Input Current (Input Low)	I <sub>I</sub> L			-50		+10	μΑ	
CLOCK OUTPUT SPECIFICATIO	NS							
		FREQSET = TTL High, VO	CC, or NC		106.25	·	MHz	
Clock Output Frequency		FREQSET = TTL Low or (	GND		212.5		IVI□∠	
Crystal Oscillation Circuit Input Capacitance					12		pF	

#### **ELECTRICAL CHARACTERISTICS (continued)**

 $(V_{CC} = +3.0 \text{V to } +3.6 \text{V}, T_A = 0^{\circ}\text{C} \text{ to } +85^{\circ}\text{C}. \text{ Typical values are at } V_{CC} = +3.3 \text{V and } T_A = +25^{\circ}\text{C}, \text{ unless otherwise noted.})$  (Note 1)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
Phase Jitter	PJ <sub>RMS</sub>	12kHz to 20MHz			0.7	1.0	psrms
Accumulated Deterministic Jitter Due to Reference Spurs					3.0		ps <sub>P-P</sub>
	10k		10kHz		3.0		
Accumulated Deterministic Jitter		(NI=+= 4)	100kHz		27	69	ps <sub>P-P</sub>
Due to Power-Supply Noise		(Note 4)	200kHz		15	43	
			1MHz		7		
Clock-Output Edge Speeds	t <sub>R</sub> , t <sub>F</sub>	20% to 80%	LVPECL outputs	250		600	ps
Clock-Output Eage Speeds			LVDS outputs	200		600	
Clock-Output Duty Cycle				49		51	%
Oscillation Startup Time		(Note 5)				5	ms
	Measured at 106.25MHz		100Hz		-90		
			1kHz		-112		
Clock-Output SSB Phase Noise		10kHz		-115		dBc/Hz	
		ivieasureu at 106.23IVITZ	100kHz		-123		UDC/FIZ
			1MHz		-142		
			10MHz		-147		

- $\textbf{Note 1:} \ \, \textbf{AC} \ \, \textbf{parameters are guaranteed by design and characterization}.$
- Note 2: Outputs are enabled and unloaded.
- Note 3: When LVPECL output is disabled to high impedance, the typical output off-current is <100µA for nominal LVPECL signal levels at the output.
- Note 4: Measured with 50mV<sub>P-P</sub> sinusoidal signal on the supply, from 10kHz to 1MHz.
- Note 5: Including oscillator startup time and PLL acquisition time, measured after V<sub>CC</sub> reaches 3.0V from power on.

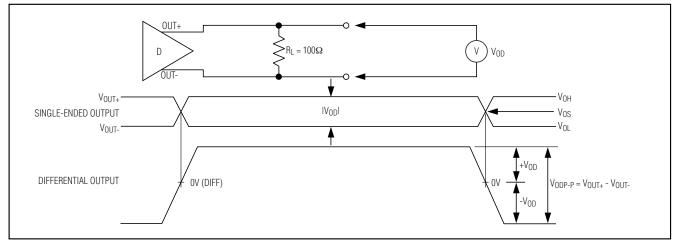
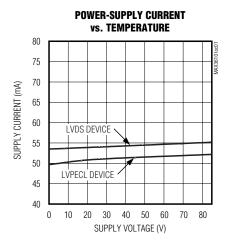
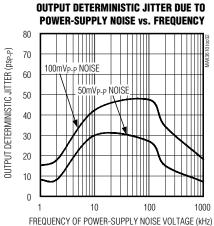


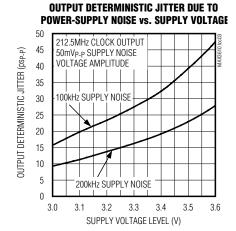
Figure 1. LVDS Swing Definitions

### **Typical Operating Characteristics**

 $(V_{CC} = 3.3V, T_A = +25^{\circ}C, unless otherwise noted.)$ 







### Pin Description

PAD	NAME	FUNCTION
1, 2, 3, 6, 7, 9, 10, 11, 15–18	N.C.	No Connection
4	X1	Crystal Oscillator Input
5	X2	Crystal Oscillator Output
8	OE	Output Enable. On-chip pullup resistor. Connect OE to logic-high, V <sub>CC</sub> , or leave open to enable the output clock. Connect OE to logic-low or GND to disable the output clock. LVPECL output clock is set to high impedance when disabled. LVDS output clock is latched to a differential high when disabled.
12	OUT-	Negative Clock Output, LVPECL or LVDS
13	GND	Ground
14	OUT+	Positive Clock Output, LVPECL or LVDS
19	FREQSET	Output Frequency Select. On-chip pullup resistor. Connect FREQSET to logic-high, V <sub>CC</sub> , or leave open to set the output clock rate to 106.25MHz. Connect FREQSET to logic-low or GND to set the output clock rate to 212.5MHz.
20	Vcc	+3.3V Supply

#### **Functional Diagram**

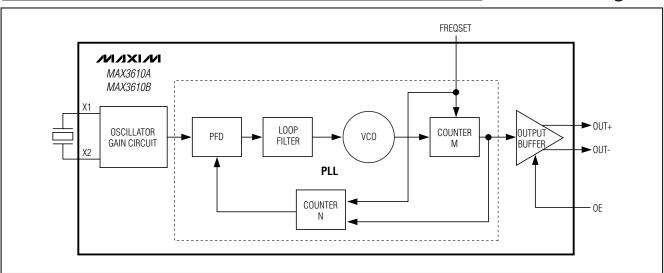


Figure 2. Functional Diagram

### **Detailed Description**

The MAX3610 contains all of the blocks needed to form a precision Fibre-Channel clock except for the external crystal, which must be supplied separately. Figure 2 shows a functional block diagram of the MAX3610. The MAX3610 consists of a crystal oscillator, a low-noise PLL, selectable clock-divider circuitry, and an output buffer.

Optimal performance is achieved by integrating the crystal oscillator with a low-noise PLL. The PLL consists of a digital phase/frequency detector (PFD) and low-jitter generation VCO. The VCO signal is scaled by clock-divider circuitry and applied to the output buffer. The MAX3610 is available with either LVPECL or LVDS output buffers (see the *Ordering Information*).

#### **Oscillator Gain Circuit**

The input capacitance of the oscillator gain circuit is trimmed to 12pF of capacitance and produces oscillations at 26.5625MHz when interfaced with the appropriate external crystal (see Table 1 for the external crystal specifications).

#### PLL

The PLL generates a 1.7GHz high-speed clock signal based on the 26.5625MHz crystal oscillator output. Clock-divider circuit M generates the output clock by

scaling the VCO output frequency. Clock-divider circuit N applies a scaled version of the output clock signal to the PFD. A TTL low applied to FREQSET, sets clock-divider M ratio to 16, and clock-divider N ratio to 8. With FREQSET pulled low, the output clock rate is 212.5MHz. A TTL high applied to FREQSET sets the clock-divider M ratio to 32, and clock-divider N ratio to 4. With FREQSET pulled high, the output clock rate is 106.25MHz.

#### **Output Drivers**

The MAX3610 is available with either LVPECL (MAX3610A) or LVDS (MAX3610B) output buffers. When not needed, the output buffers can be disabled. When disabled, the LVPECL output buffer goes to a high-impedance state. However, the LVDS outputs go to a differential 1 (OUT+ latched high and OUT- latched low) when the outputs are disabled.

#### Design Procedure

#### **Crystal Resonator Specifications**

The MAX3610 is designed to operate with an inexpensive fundamental mode crystal. Table 1 specifies the characteristics of a typical crystal to be interfaced with the MAX3610.

### **Table 1. Crystal Resonator Specifications**

PARAMETER	VALUE
Crystal	Fundamental AT-cut
Nominal Oscillator Frequency	26.5625MHz
Shunt Capacitance (Co)	2pF
Co/Cs	280
Load Capacitance (Note 6)	12pF
Equivalent Series Resistance (ESR)	$5\Omega$ to $40\Omega$
Maximum Crystal Drive Level	500μW

**Note 6:** The load capacitance includes the oscillation-circuit input capacitance, as well as the parasitic capacitance caused from the assembling/packaging of the blank crystal and IC.

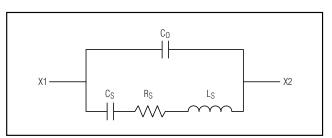


Figure 3. Equivalent Crystal Resonator Circuit Model

### **Applications Information**

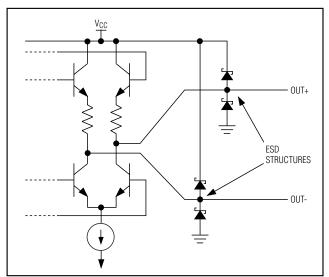


Figure 4. LVPECL Output Stage

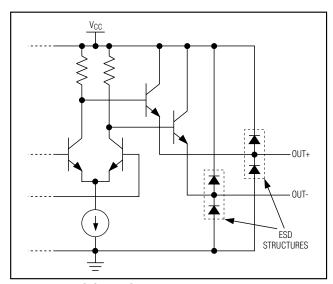


Figure 5. LVDS Output Stage

**Table 2. Bond Pad Coordinates** 

		COORDINATES			
PAD	NAME	X (μm)	Υ (μm)		
BP1	N.C.	36.1	1362.4		
BP2	N.C.	13.7	1193		
BP3	N.C.	13.7	1060		
BP4	X1	17.9	742.2		
BP5	X2	16.5	613.4		
BP6	N.C.	16.5	474.8		
BP7	N.C.	16.5	344.6		
BP8	OE	15.1	210.2		
*BP9	N.C.	16.5	39.4		
BP10	N.C.	167.7	33.8		
BP11	N.C.	1119.7	36.6		
BP12	OUT-	1613.9	50.6		
BP13	GND	1613.9	187.8		
BP14	OUT+	1613.9	325		
BP15	N.C.	1612.5	613.4		
BP16	N.C.	1611.1	753.4		
BP17	N.C.	577.9	1366.6		
BP18	N.C.	435.1	1369.4		
BP19	FREQSET	306.3	1369.4		
BP20	Vcc	169.1	1366.6		

<sup>\*</sup>Index pad

#### Pad Information

Bond pad coordinates specify center pad location. All bond pad coordinates are referenced to the lower most left corner of the index pad (see *Application Note* HFAN 9.0).

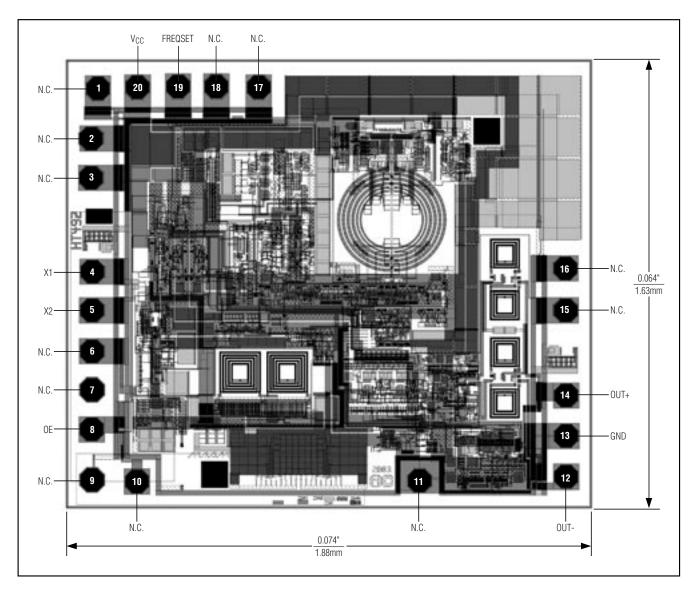
#### Chip Topography

**Package Information** 

TRANSISTOR COUNT: 2920 SUBST ELECTRICALLY ISOLATED

PROCESS: SiGe BIPOLAR
DIE SIZE: 1.88mm x 1.63mm

For the latest package outline information, go to **www.maxim-ic.com/packages**.



Maxim cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Maxim product. No circuit patent licenses are implied. Maxim reserves the right to change the circuitry and specifications without notice at any time.

8 \_\_\_\_\_\_Maxim Integrated Products, 120 San Gabriel Drive, Sunnyvale, CA 94086 408-737-7600